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Investigation of Atomic and Electron Structure of Nanocarbon Materials by Use of EXAFS and NEXAFS Spectroscopy Techniques



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- 1. Introduction. Basic Concept and Definitions.
- 2. Theoretical Background and a Little of History .
- 3. Some Aspects of Modern XAFS Experiments and XAFS Data Processing Technique.
- 4. The information that can be obtained by NEXAS/EXAFS. Some Nanocarbons Related Examples.
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I. Basic Concepts and Definitions



X-ray Absorption Spectroscopy (XAS): Basic Concepts ...





XAS of a polyimide polymer

Figure reproduced from the site <u>http://ssrl.slac.stanford.edu/stohr/nexafs.htm</u> presenting the book "J. Stöhr. NEXAFS spectroscopy. Springer, 1996" ...and Basic Definitions

Near Edge X-ray Absorption Fine Structure – NEXAFS

X-ray Absorption Near Edge Structure –XANES

Extended X-ray Absorption Fine Structure – EXAFS

Surface Extended X-ray Absorption Fine Structure – SEXAFS

> X-ray Absorption Fine Structure - XAFS



Important Details of X-ray Absorption Process



 E_{o} - energy of absorption K-edge

if Z \le 8 then
$$\tau_a \sim 10^{-15} \text{ s} \gg \tau_f \sim 10^{-13} \text{ s}$$

 $1/\tau_h = 1/\tau_a + 1/\tau_f \cong 1/\tau_a \sim 10^{-15} \text{ s}$

core-hole lifetimes

II. Theoretical Background and a Little of History



 $\mu(\hbar\omega) = \sigma_x(\hbar\omega) \cdot n_a$

 σ_x - x-ray absorption cross-section [cm²], n_a - atomic density [atoms · cm⁻³]

$$\sigma_{\rm x} \ [\rm{nm}^2] = \frac{\rm{number of absorbed photons [s^{-1}]}}{\rm{photon flux [nm^{-2} \cdot s^{-1}]}}$$

Fermi's Golden Rule
$$\Rightarrow \sigma_{\mathbf{x}}(\hbar\omega) \propto \sum_{f} \left| \left\langle \Psi_{f} \right| (\mathbf{r} \cdot \mathbf{E}) \left| \Psi_{i} \right\rangle \right|^{2} \cdot \delta(E_{f} - E_{i} - \hbar\omega)$$

 Ψ_i – initial wave function

localized state with radius $\sim a_B/Z$

 $\frac{\Psi_{f}}{f} - \text{final wave function}}{\text{delocalized state with}}$ wave number k
and wave length λ $\lambda = \frac{2\pi}{k} = \frac{2\pi}{\sqrt{\hbar\omega - E_{o}}}$

 $\frac{(\mathbf{r} \cdot \mathbf{E}) - \text{dipole transition operator}}{\mathbf{E} - \text{electric field vector}}$

for *K*-edges of C, O, N, F the only possible transition $1s \rightarrow 2p$

The Roots of Difference between NEXAFS and EXAFS

NEXAFS EXAFS $\mu(k) \propto \left| \left\langle \Psi_f \left| (\mathbf{r} \cdot \mathbf{E}) \right| \Psi_i \right\rangle \right|^2$ (multiple strong scattering regime) (single weak scattering regime) $\Psi_{f} \cong \Psi_{f}^{(0)} + \Psi_{f}^{(1)} + \Psi_{f}^{(2)} + \dots + \Psi_{f}^{(n)}, n \gg 1$ $\Psi_f \cong \Psi_f^{(0)} + \Psi_f^{(1)}$ $f(k,\theta)$ – elastic scattering amplitude small $k \rightarrow \text{large } f(k)$ large $k \rightarrow \text{small } f(k)$ $\mu(E) \propto \rho(l, E)$ $\mu(k) \sim f(k) \cdot \sin(2kR)$ NEXAFS - reflection of l - projected EXAFS - reflection of interference pattern

density of unoccupied states $\rho(l, E)$

traced along photoelectron wave number scale

NEXAFS Dependence on X-Ray Polarization



 $(\mathbf{r} \cdot \mathbf{E})$ \downarrow $\mu(E) \rightarrow \mu(\theta, E)$





the figure reproduced from R.A. Rosenberg et al.. Phys. Rev. B **33**, 4034 (1986).

Main features of CK-edge NEXAFS

- 1. π^* resonances (exciton-like) : $E_F < E_{\pi^*} < E_V$ $E_V = E_F + e\varphi$ for HOPG: $E_V = E_F + 4.7 \text{ eV}$
- 2. σ_{ex}^* core hole (Frenkel) excitons: $E_v + 1 \text{ eV} < E_{ex} < E_v + 3 \text{ eV}$ for HOPG: $E_{ex} = 291.65 \text{ eV}$

3.
$$\sigma^*$$
 - resonances : $E_v + 3 \text{ eV} < E_{\sigma^*} < E_{EXAFS}$
 E_{EXAFS} - lower boundary of EXAFS regime
for HOPG: $E_{EXAFS} \simeq E_F + 30 \text{ eV}$

<u>NEXAFS reflects:</u> x-ray polarization dependent, core hole-perturbed partial density of unoccupied states (p-DOS) localized within a few atomic sites from the excited atom ($R \sim 5$ angstrems) [*].



[*] J. Schiessling et al.. J. Phys.: Condens. Matter 15, 6563 (2003).



[*] M. Newville. Fundamentals of XAFS. University of Chicago, 2004.

EXAFS as a Quantum Interference Phenomenon



$$\begin{split} \Psi_{f} &= \Psi_{f}^{(0)} + \Psi_{f}^{(1)} \\ \Psi_{f}^{(0)} - \text{outgoing wave}, \ \Psi_{f}^{(1)} - \text{backscattered wave} \\ \Psi_{f}^{(0)} &\propto \frac{e^{i\mathbf{k}\mathbf{r}}}{r}, \qquad \Psi_{f}^{(1)} \propto f(k,\pi) \frac{e^{i(\mathbf{k}\mathbf{r}+2\delta(k))}}{r} \\ f(k,\pi) - \text{backscattering amplitude} \\ \delta(k) - \text{phase shift} \end{split}$$

$$\chi(k) \propto \left| \left\langle \Psi_f \left| (\mathbf{r} \cdot \mathbf{E}) \right| \Psi_i \right\rangle \right|^2 - \left| \left\langle \Psi_f^{(0)} \left| (\mathbf{r} \cdot \mathbf{E}) \right| \Psi_i \right\rangle \right|^2$$

Single Scattering Model

$$\chi(k) = \sum_{j} \frac{N_{j} \cdot f_{j}(k)}{kR_{j}^{2}} \cdot \sin\left(2kR_{j} + \delta_{j}(k)\right)$$

where N_j , R_j are coordination number and avarege distance to atoms in shall j

$$k_{\min} = \frac{2\pi}{R}$$
 - lower EXAFS boundary
if $R = 1.42$ Å then $k_d \cong 4.5$ Å⁻¹



Intrinsic Losses $\rightarrow S_o^2$ (shake-up and shake-off processes) S_o^2 – amplitude reduction factor;

Structural and Temperature Disorder $\rightarrow e^{-2\sigma_j^2 k^2}$ $e^{-2\sigma_j^2 k^2}$ – Debye-Waller factor σ_i^2 – mean square displasment of shall *j* atoms

Extrinsic Losses $\rightarrow e^{-2R_j/\lambda(k)}$ $\lambda(k)$ - photoelectron mean free path determined by inelastic scatterings and finite core-hole lifetime

$$\chi(k) = S_o^2 \cdot \sum_j \frac{N_j \cdot f_j(k) \cdot e^{-2\sigma_j^2 k^2} \cdot e^{-2R_j/\lambda(k)}}{kR_j^2} \sin\left(2kR_j + \delta_j(k)\right)$$

The figure reproduced from M. Newville. Fundamentals of XAFS. University of Chicago, 2004.

Extraction of Structural Parameters from $\chi(k)$ - function

Radial structure function F(R) can be obtained using Fourier transformation of $k\chi(k)$ [*]:

$$F(R) = \int_{k_{\min}}^{k_{\max}} dk (k\chi(k)) \cdot \sin(2kR)$$

 k_{\min} and k_{\max} are determined, respectively, by lower EXAFS boundary and by acceptable value of signal/noise ratio



[*]- D. E. Sayers,, E. A. Stern, and F. W. Lytle, Phys. Rev. Lett. 27, 1204 (1971).



The figures reproduced from P. Castrucci et al. Phys. Rev. B **75**, 035420 (2007).

The Key Points of NEXAFS/EXAFS History

Discovery of X-Rays - Röntgen (1895)

First measurements of absorption edge – Maurice de Brogelie (1913)

The first observation of the fine structure - Fricke (K-edges) (1920), Hertz (L-edges) (1920)

The first theory of NEXAFS ("Kossel structure") and EXAFS ("Kronig Structure") -

Kossel (1920), R. Kronig (1931)

Improvement of theoretical models and experimental facilities (1930s – 1960s)

Creation of valid shot-range-order theory of EXAFS – D. Sayers, E. Stern, F. Lytle (1968-1971)

Appearance of the name EXAFS - F. Lytle, J. Prins (1968)

The dawn of "Synchrotron Era" – (1970s)

Appearance of the names XANES/NEXAFS - A. Bianconi (1980)/J. Stöhr(1982)

Development of highly quantitative multiple-scattering theories of XAFS – (1980s - present time)

III. Some Aspects of Modern XAFS Experiments and XAFS Data Processing Technique



X-ray beam line Experimental station Electron beam Electron beam Linear accelerator Booster ring Electron gun Undulator Magnets

Storage Ring Scheme

The figure taken from site: http://www.odec.ca/projects/2005/shar5a0/ public_html/images /model_animated.gif Synchrotron's Characteristics:

Electron beam energy:	E_e [GeV]
Current:	i _e [mA]
Circumference:	<u>L</u> [m]
Pulse duration (FWHM):	au (ps)
Bending Magnet Field :	B [T]

Critical Photon Energy : $E_{\rm C}$ [keV]Total Photon Flux:F [photons/s]

 $L = 2\pi R$

$$E_{\rm C} = \hbar \,\omega_{\rm C} = 0.665 \cdot E_e^2 \cdot B$$
$$F \cong 1.3 \cdot 10^{17} \cdot i_e \cdot E_e$$

Main Characteristic of Synchroton Radiation







1. linear polarization of **E** (in the plane of e^- orbit)

2. extrimely high brightness ($\sim 10^{10}$ brighter than the most powerful laboratory source)

Monochromatization of Synchrotron Radiation



Typical Parameters of Third Generation Synchrotrons

Facility	ALS	BESSY II	ESRF	SPring-8
Country	USA	Germany	France	Japan
Electron energy	1.90 GeV	1.70 GeV	6.04 GeV	8.00 GeV
Current (mA)	400	200	300	100
Circumference (m)	197	240	884	1440
RF frequency (MHz)	500	500	352	509
Pulse duration (FWHM) (ps)	35-70	20-50	70	120
Bending magnet field (T)	1.27	1.30	0.806	0.679
Critical photon energy (keV)	3.05	2.50	19.6	28.9
Bending magnet sources	24	32	32	23

The Table taken from prof. D. Attwood lecture "Intro to Synchrotron Radiation" EE290F, 16 Jan 2007. Berkeley. USA.

Recording of the XAS in the Reflection Mode



$$I_{abs}(\hbar\omega) \propto \mathbf{Y}_{e}(\hbar\omega) \propto \mathbf{Y}_{f}(\hbar\omega)$$

 $Y_f(\hbar\omega)$ – fluorecence yeild (FY) $Y_e(\hbar\omega)$ – electron yeild (EY)

$$\begin{split} D_e \ll D_f \sim 1/\mu(\hbar\omega') \\ \text{if } Z \leq 16 \quad \mathrm{Y}_f(\hbar\omega) \ll \mathrm{Y}_e(\hbar\omega) \end{split}$$

 $\longleftarrow Y_{tot}(\hbar\omega) = Y_e(\hbar\omega, \ 0 \le E_e \le \hbar\omega - e\varphi)$

TEY - Total Electron Yield TFY - Total Fluorecence Yield



se, *pe*, *ae* – secondary, photo and auger electrons.

 $\mathbf{Y}_{tot} = \mathbf{Y}_{se} + \mathbf{Y}_{ae} + \mathbf{Y}_{pe} \gg \mathbf{Y}_{ae} + \mathbf{Y}_{pe}$

e⁻ escape depth D_e = XAS information depth
1. TEY:
$$\mu(\hbar\omega) \propto Y_{tot}(\hbar\omega)/I_o \rightarrow D_e \approx 50 \text{ Å}$$

2. PEY: $\mu(\hbar\omega) \propto Y_{part}(\hbar\omega)/I_o \rightarrow 10 \text{ Å} \leq D_e \leq 50 \text{ Å}$
3. AEY: $\mu(\hbar\omega) \propto Y_{ae}(\hbar\omega)/I_o \rightarrow D_e \sim 10 \text{ Å}$
↓

Choice of XAS recording mode determines its information depth

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TEY - Surface + Bulk
TFY - Bulk
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Normalization and Background Correction of the XAS



Measured electron yeild $Y_{e}(\hbar\omega)$ must be corrected for beam line transmission function $T(\hbar\omega)$



for CK-edge NEXAFS $\mu(\hbar\omega, Au) \simeq const$

Normalization and Background Correction of the XAS



 $Y_{samp}^{ref}(\hbar\omega)$ – more simple and controllable $Y_{grid}^{ref}(\hbar\omega)$ – accounts for photon flux instabilities



Analysis and Interpretation of NEXAFS Spectra



[*] For details see references [1-4] from Main Sources.

IV. The information that can be obtained by NEXAS/EXAFS Spectroscopy. Some Nanocarbons Related Examples





narrow π^* and σ^* resonaces show that solid C₆₀ and C₇₀ are the molecular crystals



[**] T. Kaambre et al. Phys. Rev. B **75**, e195432 (2007).

Experimental and Theoretical study NEXAFS of C₆₀F₃₆[*]



J. Chem. Phys. 130, 014704 (2009).



[*] M. M. Brzhezinskaya et al. Phys. Rev. B 79, 155439 (2009).

Study of metallicity-sorted SWCNT [*]



XAS of metallic (M) and semiconducting (S) SWCNTs

High-resolution XAS C1s absorption edges together with the results of a line shape analysis (thin lines) and TB DOS broadened by the experimental resolution.

[*] P. Ayala et al. Phys. Rev. B 80, 205427 (2009).

CK-edge NEXAFS of Few Layer Graphene (FGL) [*]





[*] D. Pacile et al., Phys. Rev. Lett. 101, 066806 (2008).

NEXAFS study of FLG Grown on 6H-SiC(0001) [*]

CK-edge NEXAFS spectra measured at different incident angles



4th annealing at T=1400°C (formation of thick graphene layer)

3rd annealing at T=1180°C (growth of single phase graphene layers)

2nd annealing at T=1080°C (formation of mixed phase (buffer) layer)

1st annealing at $T = 900^{\circ}C$ (for substrate outgasing).

[*]. Ki-jeong Kim. J. Phys.: Condens. Matter 20, 225017 (2008).

EXAFS study of I-doped SWNTs [*]



 ΔE

R

12.11

2.74

2.8

3.02

[*] T. Michel et al. Phys. Rev. B 73, 195419 (2006).

V. CONCLUSIONS

- 1. Modern NEXAFS spectroscopy proved to be one of the most powerful experimental techniques widely used for investigation of nanocarbon materials. It makes possible to probe not only their local electronic structure, but also a chemical composition and even atomic structure.
- 2. Application of EXAFS spectroscopy in this area of research is much more restricted. As a rule, this technique is used for probing a local atomic structure of composite materials, which along with the carbon atoms contain also the atoms of higher Z elements (such Fe, Ru, I) characterizing by much higher values of absorption edge energy and backscattering amplitude.

VI. MAIN SOURCES:

- 1. J. Stöhr. NEXAFS spectroscopy. Springer, 1996.
- 2. M. Newville. Fundamentals of XAFS. University of Chicago, 2004.
- 3. J. J. Rehr, R. C. Albers. Theoretical approaches to x-ray absorption fine structure. Reviews of Modern Physics, **72**, 621 (2000).
- X-ray Absorption: Principles, Applications, Techniques of EXAFS, SEXAFS, and XANES, in Chemical Analysis, D. C. Koningsberger and R. Prins, ed., John. Wiley & Sons, 1988.
- 5. F.W. Lytle. The EXAFS family tree: a personal history of the development of extended X-ray absorption fine structure. J. Synchrotron Rad. **6**, 123 (1999).

Interior view of Synchrotron BESSY II



Experimental Station of Russian-German Beam Line

